

WS7931D

CMOS Medium Band LTE LNA

<http://www.sh-willsemi.com>

Descriptions

The WS7931D is a low noise amplifier (LNA) for LTE receiver applications, available in a small 6-pin DFN package. The WS7931D requires only one external inductor for input matching.

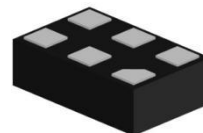
The WS7931D is designed to achieve low power dissipation and good performance. It is designed and optimized for the LTE medium band: 1805MHz to 2200MHz.

Features

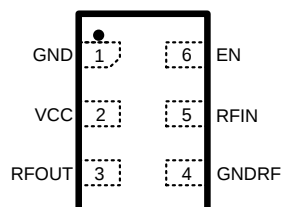
- Operating frequency: 1805 MHz to 2200 MHz
- Noise figure = 1.0 dB
- Gain = 12.5 dB
- Input 1 dB compression point = -3.5 dBm
- In-band input IP3 = +5.0 dBm
- Supply voltage: 1.8 V to 3.1 V
- Integrated supply decoupling capacitor
- Supply current: 6.4 mA
- Power-down mode leakage current < 1μA
- One external matching inductor required
- ESD protection: HBM > 2.0kV for all pins
- Integrated output matching
- Package: 6-pin DFN, 1.1 x 0.7 x 0.55 mm³
- Process: CMOS

Applications

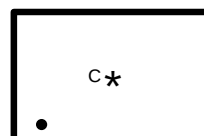
- Cell phones
- Tablets
- Other RF front-end modules



DFN1107-6L (Bottom view)



Pin configuration (Top view)



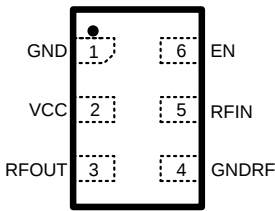
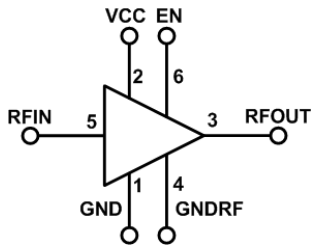
C = Device code
* = Month code (A~Z)

Marking (Top view)

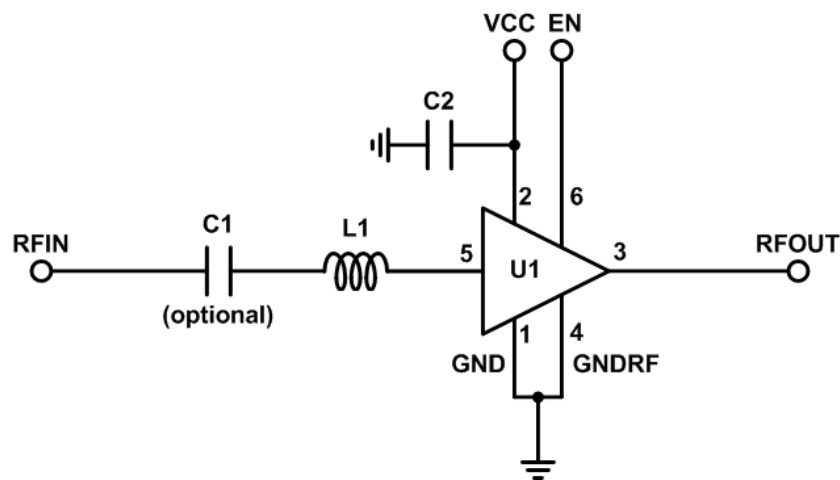
Order information

Device	Package	Shipping
WS7931D-6/TR	DFN1107-6L	10000/Reel&Tape

Pinning Information

Pin	Description	Transparent top view	Symbol view
1	GND		
2	VCC		
3	RFOUT		
4	GNDRF		
5	RFIN		
6	EN		

Application Information



Symbol	Description	Footprint	Value	Supplier	Comment
U1	WS7931D	1.1x0.7x0.55 mm ³	N/A	Will-Semi	DUT
C1	Capacitor	0402	1 nF	Various	DC blocking
C2	Capacitor	0402	1 nF	Various	Supply decoupling
L1	Inductor	0402	8.2 nH	Murata LQW15	Input matching

Quick Reference Data

Freq = 2000 MHz; $V_{CC} = 2.8\text{ V}$; $V_{EN} > 2V_{CC}/3$; Temp = 25°C; input matched to 50 Ω with an 8.2 nH inductor. The condition is applied unless otherwise specified.

Symbol	Parameter	Condition	Min	Typ	Max	Unit
V_{CC}	Supply voltage		1.8	2.8	3.1	V
I_{CC}	Supply current			6.4		mA
G_p	Power gain	f = 2000 MHz		12.5		dB
NF	Noise figure	f = 2000 MHz		1.0		dB
IP _{1dB}	Input power at 1 dB gain compression			-3.5		dBm
IIP ₃	Input third-order intercept point			+5.0		dBm

Recommended Operating Conditions

Symbol	Parameter	Condition	Min	Typ	Max	Unit
V_{CC}	Supply voltage		1.8		3.1	V
Temp	Ambient temperature		-40	+25	+85	°C
V_{EN}	Input voltage on pin 6 (EN)	OFF state		0	$V_{CC}/3$	V
		ON state	$2V_{CC}/3$	V_{CC}		V

Absolute Maximum Ratings

Maximum ratings are absolute ratings, exceeding only one of these values may cause irreversible damage to the integrated circuit.

Symbol	Parameter	Condition	Min	Max	Unit
V_{CC}	Supply voltage		-0.3	3.1	V
V_{EN}	Input voltage on pin EN		-0.3	3.1	V
V_{RFIN}	Input voltage on pin RFIN		-0.3	3.1	V
V_{RFOUT}	Input voltage on pin RFOUT		-0.3	3.1	V
P_{in}	RF input power			0	dBm
T_{STG}	Storage temperature		-65	+150	°C
T_J	Junction temperature			150	°C
V_{ESD}	ESD capability all pins	Human Body Model (HBM)		± 2000	V

Characteristics

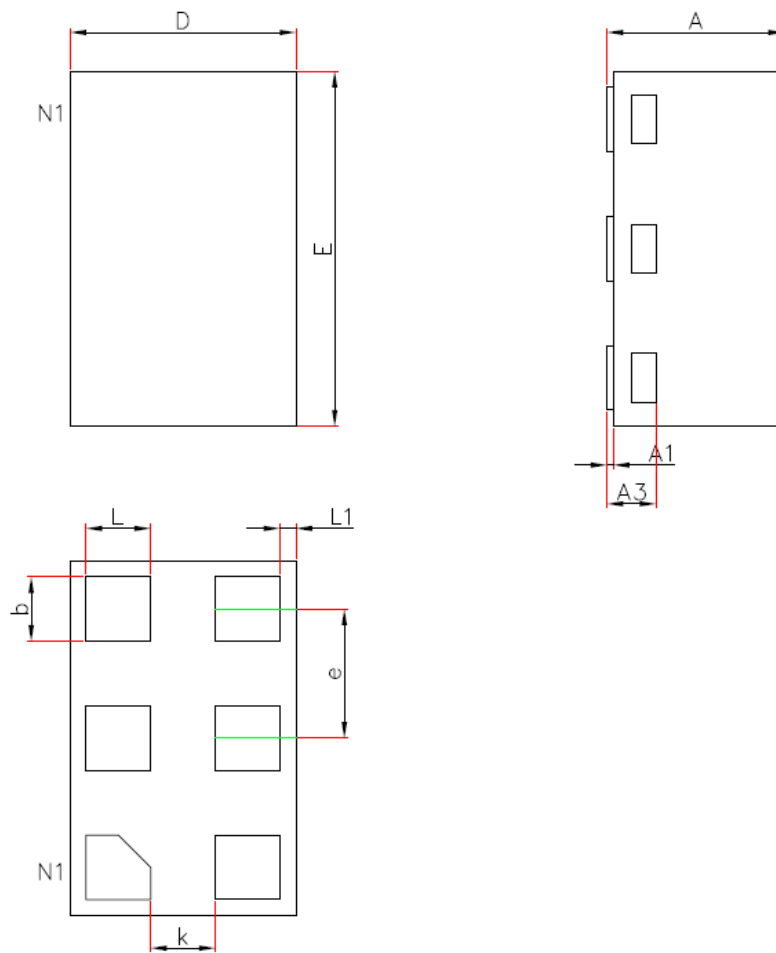
1805 MHz $\leq f \leq$ 2200 MHz; $V_{CC} = 2.8$ V; $V_{EN} > 2V_{CC}/3$; Temp = 25°C; input matched to 50 Ω with an 8.2 nH inductor; The condition is applied unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_{CC}	Supply current	On state		6.4		mA
		Off state			1	μ A
$G_p^{[4]}$	Power gain	f = 1850 MHz		12.5		dB
		f = 2150 MHz		12.1		dB
RL_{in}	Input return loss	f = 1850 MHz		9.0		dB
		f = 2150 MHz		8.0		dB
RL_{out}	Output return loss	f = 1850 MHz		11.0		dB
		f = 2150 MHz		24.0		dB
ISL	Reverse isolation	f = 1850 MHz		34.5		dB
		f = 2150 MHz		34.0		dB
NF	Noise figure	f = 1850 MHz		0.95		dB
		f = 2150 MHz		1.0		dB
IP_{1dB}	Input power at 1 dB gain compression	f = 1850 MHz		-3.5		dBm
		f = 2150 MHz		-2.5		dBm
IIP_3	Input third-order intercept point	f = 1850 MHz ^[1]		+4.0		dBm
		f = 2150 MHz ^[2]		+5.0		dBm
K	Rollett stability factor ^[3]		1			
t_{on}	Turn-on time				5	μ s
t_{off}	Turn-off time				5	μ s

[1] $f_1 = 1840$ MHz, $f_2 = 1850$ MHz, $P_{in} = -25$ dBm

[2] $f_1 = 2140$ MHz, $f_2 = 2150$ MHz, $P_{in} = -25$ dBm

[3] 10M~20GHz

Package Outline Dimensions
DFN1107-6L


Symbol	Dimensions In Millimeters		
	Min.	Typ.	Max.
A	0.500	0.550	0.600
A1	0.000	0.025	0.050
A3	0.152REF		
b	0.150	0.200	0.250
D	0.600	0.700	0.800
E	1.000	1.100	1.200
e	0.400BSC		
k	0.200REF		
L	0.124	0.200	0.276
L1	0.050REF		

